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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

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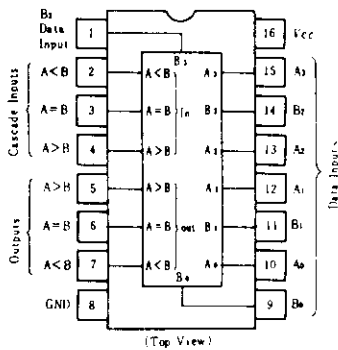
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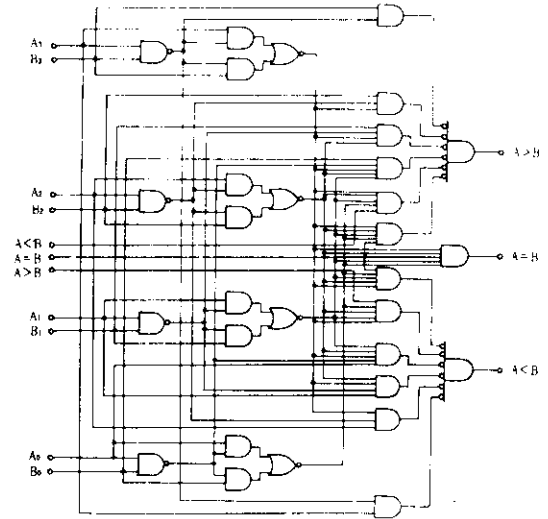
HD74LS85 • 4-bit Magnitude Comparators

This four bit magnitude comparator performs comparison of straight binary and straight BCD (8-4-2-1) codes. Three fully decoded decisions about two 4-bit words (A, B) are made and are externally available at three outputs. This device is fully expandable to any number of bits without external gates. Words of greater length may be compared by connecting comparators in cascade. The $A > B$, $A < B$, and $A = B$ outputs of a stage handling less-significant bits. The stage handling the least-significant bits must have a high-level voltage applied to the $A \geq B$ input. The cascading path is implemented with only a two-gate-level delay to reduce overall comparison times for long words.

PIN ARRANGEMENT



BLOCK DIAGRAM



FUNCTION TABLE

Inputs				Cascading inputs			Outputs		
A_3, B_3	A_2, B_2	A_1, B_1	A_0, B_0	$A < B$	$A < B$	$A = B$	$A > B$	$A < B$	$A = B$
$A_3 > B_3$	X	X	X	X	X	X	H	L	L
$A_3 < B_3$	X	X	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 > B_2$	X	X	X	X	X	H	L	L
$A_3 = B_3$	$A_2 < B_2$	X	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 > B_1$	X	X	X	X	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 < B_1$	X	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 > B_0$	X	X	X	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 < B_0$	X	X	X	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	H	L	L	H	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	L	H	L	L	H	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	X	X	H	L	L	H
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	H	H	L	L	L	L
$A_3 = B_3$	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	L	L	L	H	H	L

H; high level, L; low level, X; irrelevant

ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$)

Item		Symbol	Test Conditions	min	typ*	max	Unit
Input voltage		V_{IH}		2.0	—	—	V
		V_{IL}		—	—	0.8	V
Output voltage		V_{OH}	$V_{CC} = 4.75\text{V}$, $V_{IH} = 2\text{V}$, $V_{IL} = 0.8\text{V}$, $I_{OH} = -400\mu\text{A}$	2.7	—	—	V
		V_{OL}	$V_{CC} = 4.75\text{V}$, $V_{IH} = 2\text{V}$	—	—	0.4	V
			$V_{IL} = 0.8\text{V}$	—	—	0.5	
Input current	A < B, A > B Inputs	I_{IH}	$V_{CC} = 5.25\text{V}$, $V_I = 2.7\text{V}$	—	—	20	μA
	Other inputs			—	—	60	
	A < B, A > B Inputs	I_{IL}	$V_{CC} = 5.25\text{V}$, $V_I = 0.4\text{V}$	—	—	-0.4	mA
	Other inputs			—	—	-1.2	
	A < B, A > B Inputs	I_I	$V_{CC} = 5.25\text{V}$, $V_I = 7\text{V}$	—	—	0.1	mA
	Other inputs			—	—	0.3	
Short-circuit output current		I_{OS}	$V_{CC} = 5.25\text{V}$	-20	—	-100	mA
Supply current **		I_{CC}	$V_{CC} = 5.25\text{V}$	—	10.4	20	mA
Input clamp voltage		V_{IK}	$V_{CC} = 4.75\text{V}$, $I_{IK} = -18\text{mA}$	—	—	-1.5	V

* $V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$

** I_{CC} is measured with outputs open, A=B grounded, and all other inputs at 4.5V.

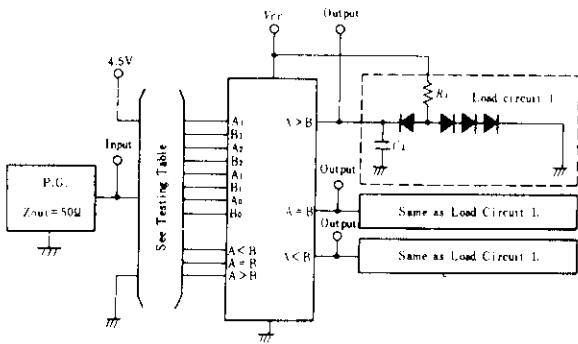
SWITCHING CHARACTERISTICS ($V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Inputs	Outputs	Number of gate levels	Test Conditions	min	typ	max	Unit
Propagation delay time	t_{PLH}	Any A or B data Input	A < B, A > B	1	$C_L = 15\text{pF}$ $R_L = 2\text{k}\Omega$	—	14	—	ns
				2		—	19	—	
				3		—	24	36	
			A = B	4		—	27	45	
	t_{PHL}	Any A or B data Input	A < B, A > B	1		—	11	—	ns
				2		—	15	—	
				3		—	20	30	
			A = B	4		—	23	45	
	t_{PLH}	A < B or A = B	A > B	1		—	14	22	ns
	t_{PHL}	A < B or A = B	A > B	1		—	11	17	ns
	t_{PLH}	A = B	A = B	2		—	13	20	ns
	t_{PHL}	A = B	A = B	2		—	13	26	ns
	t_{PLH}	A > B or A = B	A < B	1		—	14	22	ns
	t_{PHL}	A > B or A = B	A < B	1		—	11	17	ns

HD74LS85

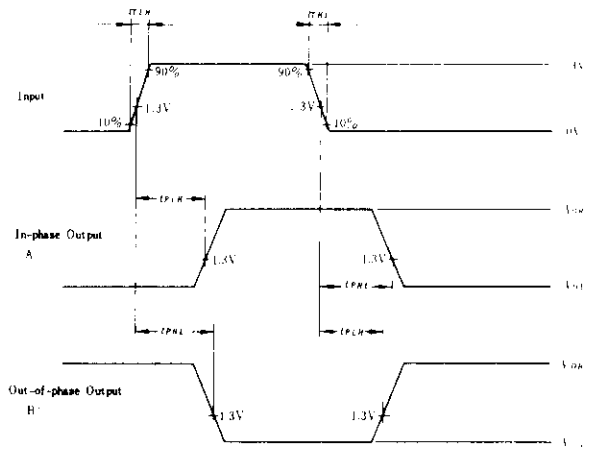
■ TESTING METHOD

1) Test Circuit



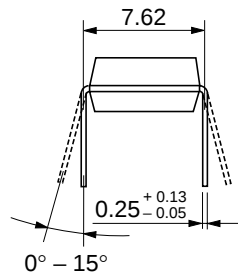
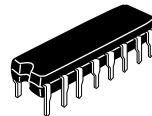
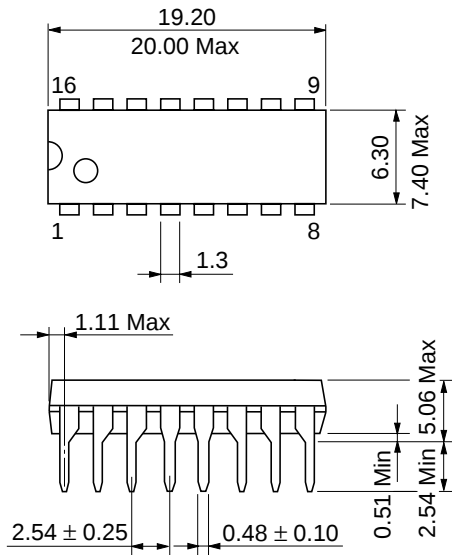
- Notes) 1. Input pulse; $t_{TLH} \leq 15\text{ns}$, $t_{THL} \leq 6\text{ns}$, $PRR = 1\text{MHz}$, duty cycle = 50%
2. C_L includes probe and jig capacitance.
3. All diodes are 1S2074 Ⓢ .

Waveform

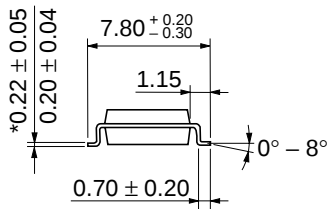
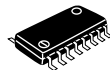
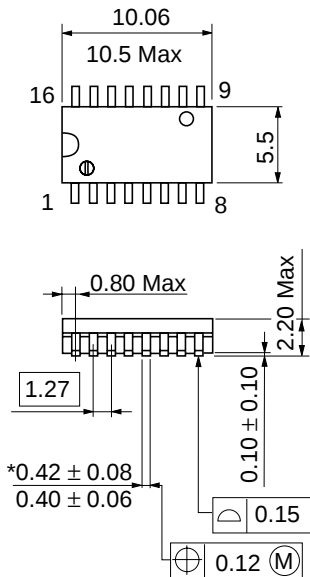


2) Testing Table

Item	Inputs											Output Waveforms		
	A ₃	B ₃	A ₂	B ₂	A ₁	B ₁	A ₀	B ₀	A > B	A = B	A < B	A > B	A = B	A < B
t _{PLH} t _{PHL}	IN	4.5V	4.5V	GND	GND	GND	GND	GND	GND	GND	GND	A		B
	4.5V	IN	GND	4.5V	GND	GND	GND	GND	GND	GND	GND	B		A
	GND	GND	IN	4.5V	4.5V	GND	GND	GND	GND	GND	GND	A		B
	GND	GND	4.5V	IN	GND	4.5V	GND	GND	GND	GND	GND	B		A
	GND	GND	GND	GND	IN	4.5V	4.5V	GND	GND	GND	GND	A		B
	GND	GND	GND	GND	4.5V	IN	GND	4.5V	GND	GND	GND	B		A
	GND	GND	GND	GND	GND	GND	IN	4.5V	4.5V	GND	GND	A		B
	GND	GND	GND	GND	GND	GND	4.5V	IN	GND	GND	4.5V	B		A
	GND	GND	GND	GND	GND	GND	IN	4.5V	GND	4.5V	GND		A	B
	GND	GND	GND	GND	GND	GND	4.5V	IN	GND	4.5V	GND	B	A	
	GND	GND	GND	GND	GND	GND	GND	GND	IN	GND	GND			B
	GND	GND	GND	GND	GND	GND	GND	GND	GND	IN	GND	B	A	B

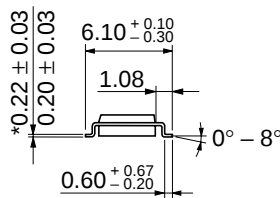
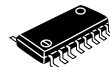
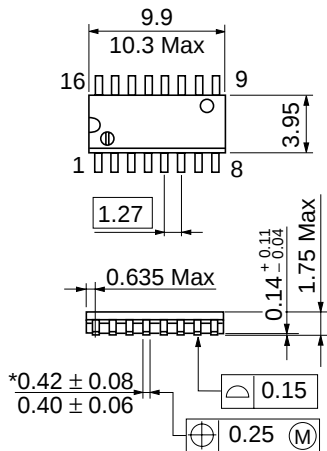


Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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